



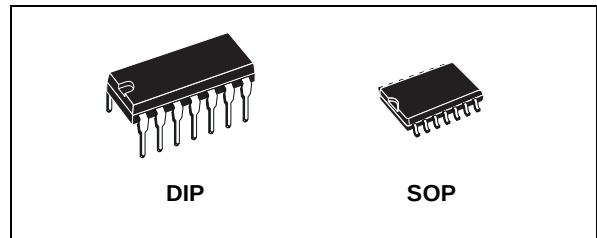
HCF4041UB

QUAD TRUE/COMPLEMENT BUFFER

- BALANCED SINK AND SOURCE CURRENT: APPROXIMATELY 4 TIMES STANDARD "B" DRIVE
- EQUALIZED DELAY TO TRUE AND COMPLEMENT OUTPUTS
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT
 $I_I = 100\text{nA (MAX) AT } V_{DD} = 18\text{V } T_A = 25^\circ\text{C}$
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"

DESCRIPTION

The HCF4041UB is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. The HCF4041UB is a QUAD TRUE/COMPLEMENT buffer consisting of n and p channel units having low channel resistance and

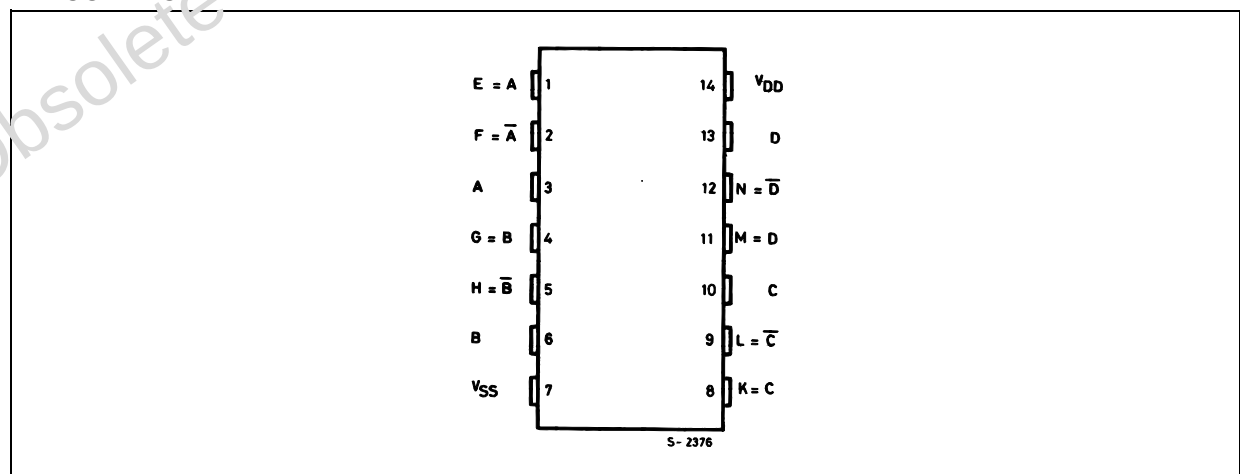


ORDER CODES

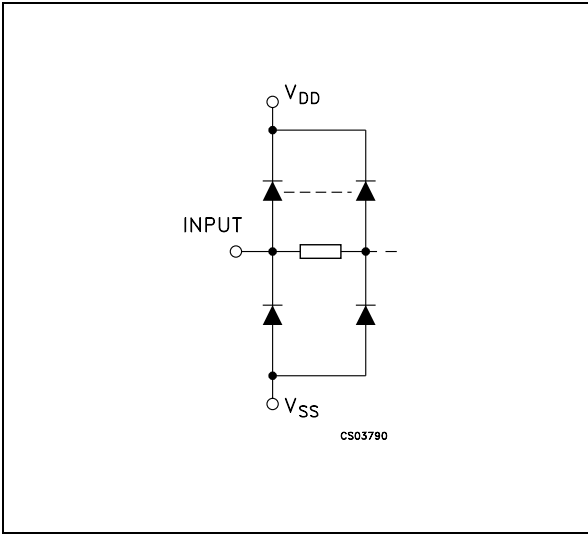
PACKAGE	TUBE	1 & R
DIP	HCF4041UBEY	
SOP	HCF4041UBM1	HCF4041UM013TR

high current (sourcing and sinking) capability. This device is intended for use as a buffer, line driver, or CMOS to TTL driver. It can be used as an ultra-low power resistor network driver for A/D and D/A conversion, as a transmission line driver, and in other applications where high noise immunity and low power dissipation are primary design requirements.

PIN CONNECTION



INPUT EQUIVALENT CIRCUIT



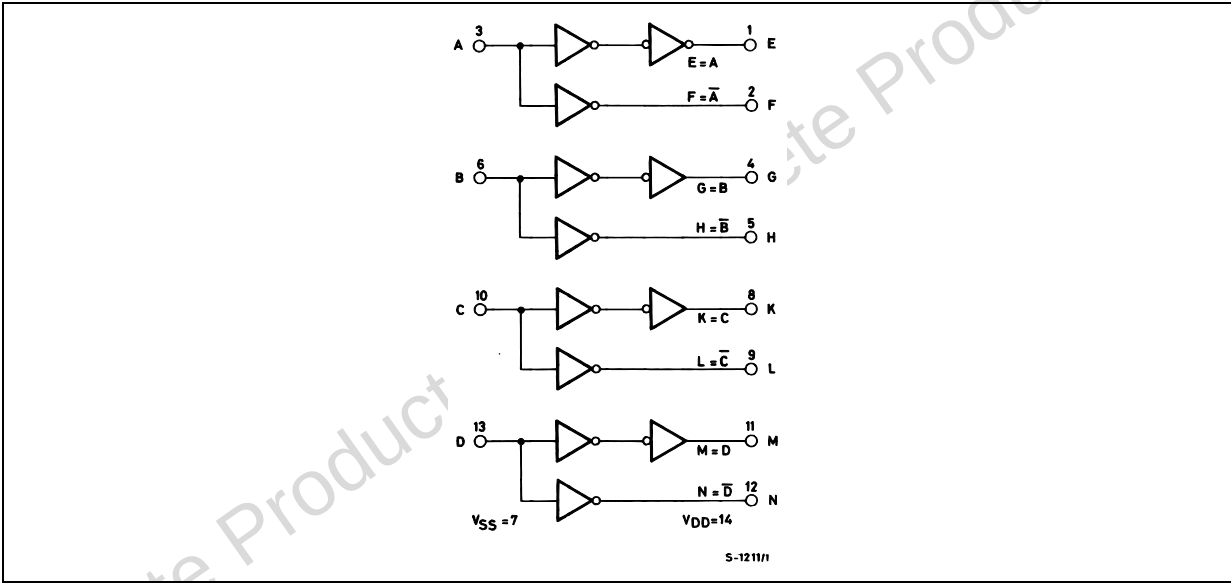
PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
3, 6, 10, 13	A, B, C, D	Data Inputs
1, 4, 8, 11	E, G, K, M	Data Outputs (TRUE)
2, 5, 9, 12	F, H, L, N	Data Outputs (COMPLEMENT)
7	V _{SS}	Negative Supply Voltage
14	V _{DD}	Positive Supply Voltage

TRUTH TABLE

INPUTS	OUTPUTS (TRUE)	OUTPUTS (COMPLEMENT)
A, B, C, D	E, G, K, M	F, H, L, N
H	H	L
L	L	H

FUNCTIONAL DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
V _I	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.
All voltage values are referred to V_{SS} pin voltage.



RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V_I	Input Voltage	0 to V_{DD}	V
T_{op}	Operating Temperature	-55 to 125	°C

DC SPECIFICATIONS

Symbol	Parameter	Test Condition				Value								Unit
		V _I (V)	V _O (V)	I _{OL} (μA)	V _{DD} (V)	T _A = 25°C			-40 to 85°C		-55 to 125°C			
						Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
I _L	Quiescent Current	0/5			5		0.02	1		30		30	μA	
		0/10			10		0.02	2		60		60		
		0/15			15		0.02	4		120		120		
		0/20			20		0.04	20		600		600		
V _{OH}	High Level Output Voltage	0/5		<1	5	4.95			4.95		4.95		V	
		0/10		<1	10	9.95			9.95		9.95			
		0/15		<1	15	14.95			14.95		14.95			
V _{OL}	Low Level Output Voltage	5/0		<1	5		0.05			0.05		0.05	V	
		10/0		<1	10		0.05			0.05		0.05		
		15/0		<1	15		0.05			0.05		0.05		
V _{IH}	High Level Input Voltage		0.5/4.5	<1	5	4			4		4		V	
			1/9	<1	10	8			8		8			
			1.5/13.5	<1	15	12.5			12.5		12.5			
V _{IL}	Low Level Input Voltage		4.5/0.5	<1	5			1		1		1	V	
			9/1	<1	10			2		2		2		
			13.5/1.5	<1	15			2.5		2.5		2.5		
I _{OH}	Output Drive Current	0/5	2.5	<1	5	-5.44	-12.8		-4.08		-4.08		mA	
		0/5	4.6	<1	5	-1.36	-3.2		-1.02		-1.02			
		0/10	9.5	<1	10	-4.25	-10		-3.18		-3.18			
		0/15	13.5	<1	15	-16.1	-38		-12.1		-12.1			
I _{OL}	Output Sink Current	0/5	0.4	<1	5	1.36	3.2		1.02		1.02		mA	
		0/10	0.5	<1	10	4.25	10		3.18		3.18			
		0/15	1.5	<1	15	16.1	38		12.11		12.11			
I _I	Input Leakage Current	0/18	Any Input		18		±10 ⁻⁵	±0.1		±1		±1	μA	
C _I	Input Capacitance		Any Input				15	22.5					pF	

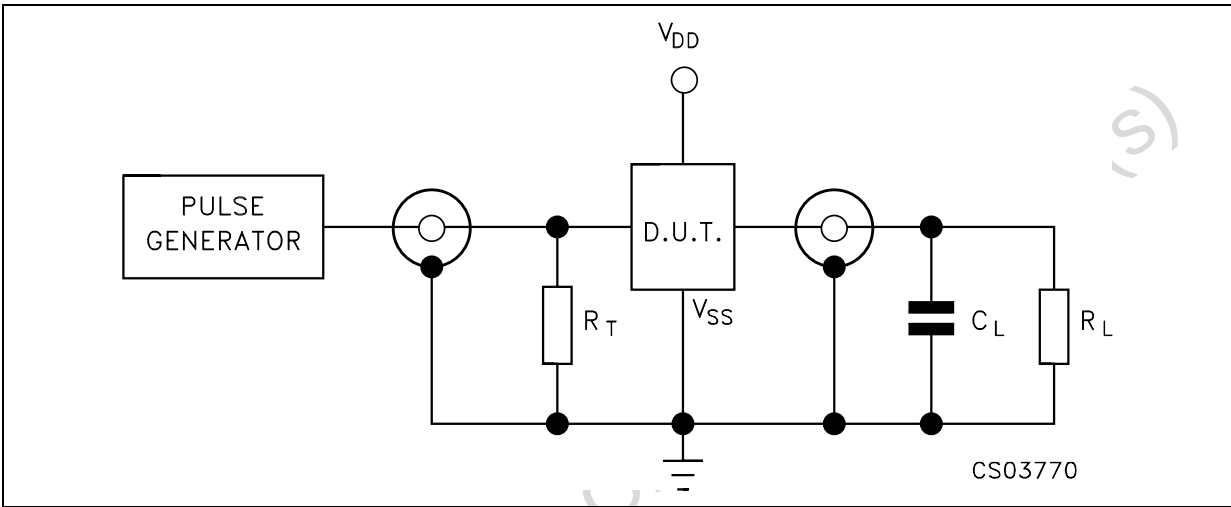
The Noise Margin for both "1" and "0" level is: 1V min. with $V_{DD}=5V$, 2V min. with $V_{DD}=10V$, 2.5V min. with $V_{DD}=15V$

DYNAMIC ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C, C_L = 50pF, R_L = 200KΩ, t_r = t_f = 20 ns)

Symbol	Parameter	Test Condition		Value (*)			Unit
		V _{DD} (V)		Min.	Typ.	Max.	
t _{PLH} t _{PHL}	Propagation Delay Time	5			60	120	ns
		10			35	70	
		15			25	50	
t _{TLH} t _{THL}	Output Transition Time	5			40	80	ns
		10			20	40	
		15			15	30	

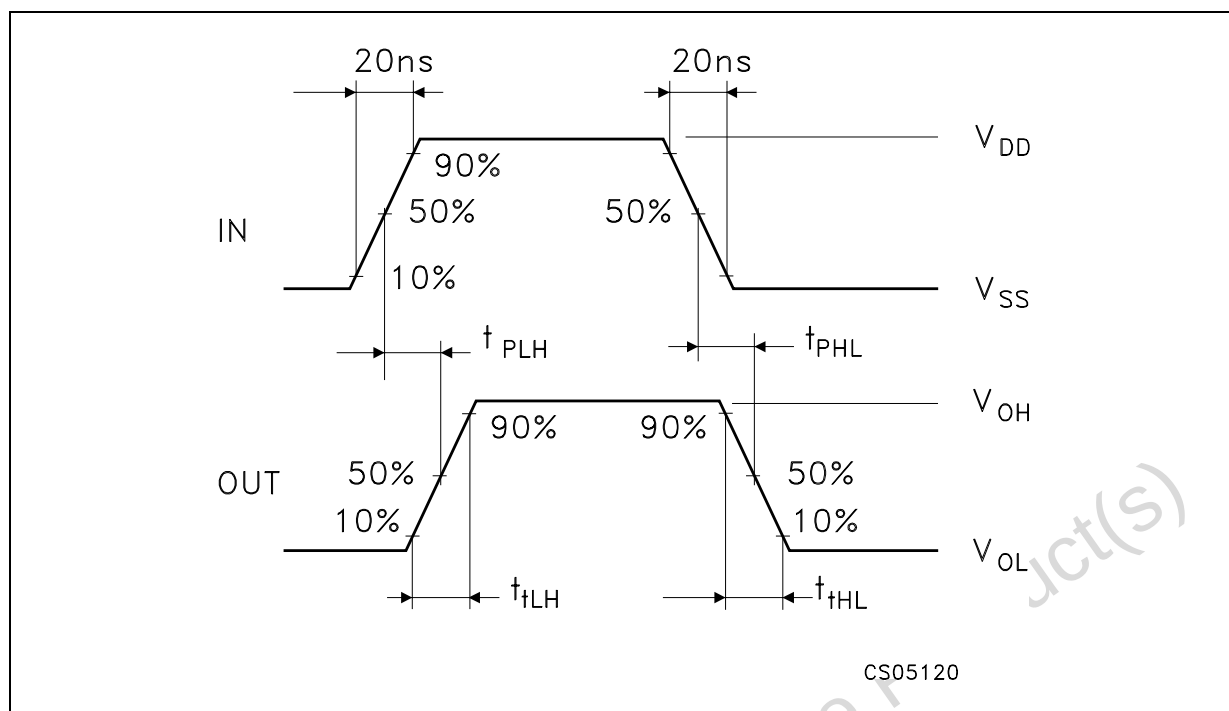
(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.

TEST CIRCUIT

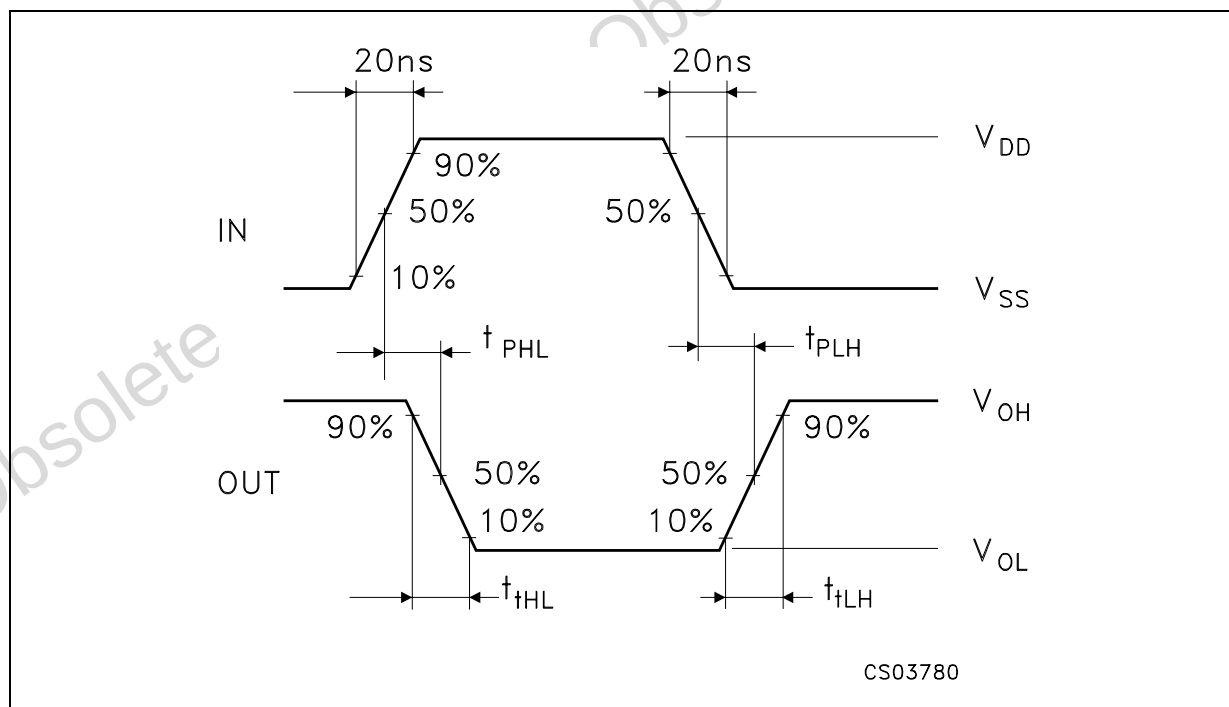


C_L = 50pF or equivalent (includes jig and probe capacitance)
R_L = 200KΩ
R_T = Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM 1 : PROPAGATION DELAY TIMES FOR NON INVERTING CONDITIONS ($f=1\text{MHz}$; 50% duty cycle)

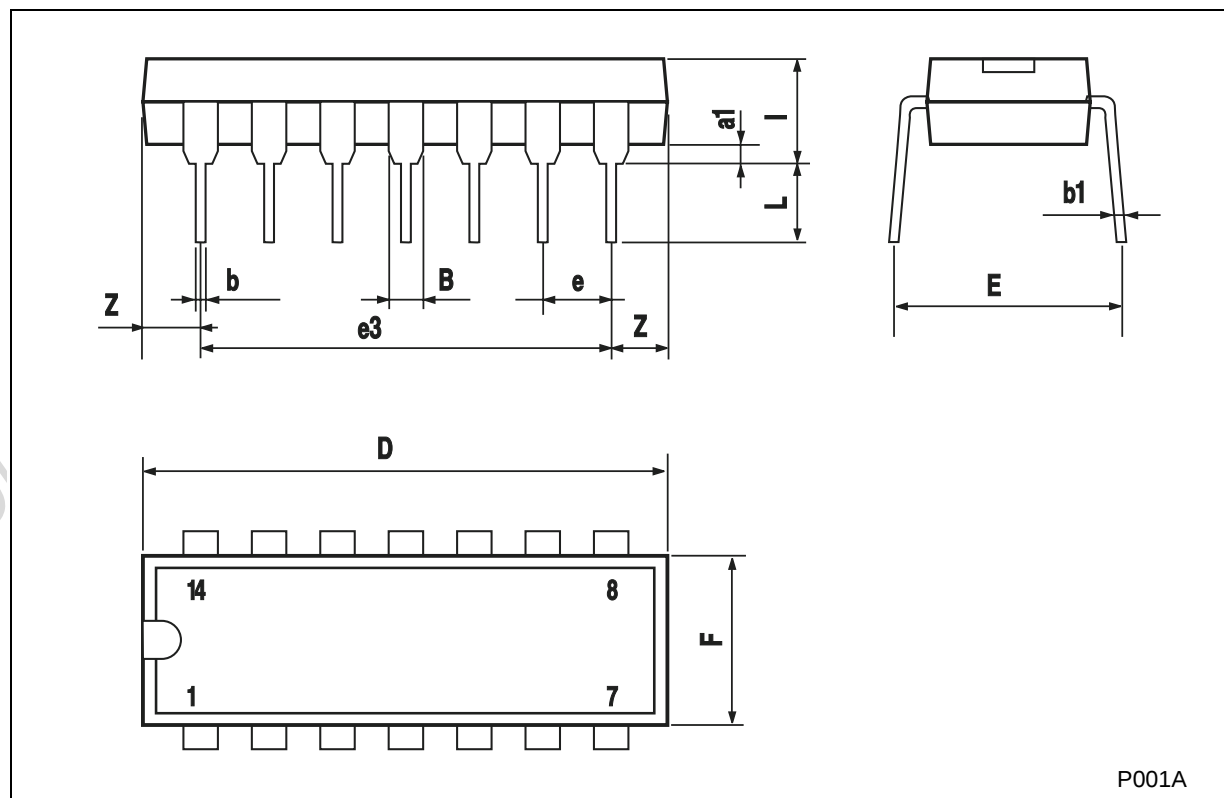


WAVEFORM 2 : PROPAGATION DELAY TIMES FOR INVERTING CONDITIONS ($f=1\text{MHz}$; 50% duty cycle)



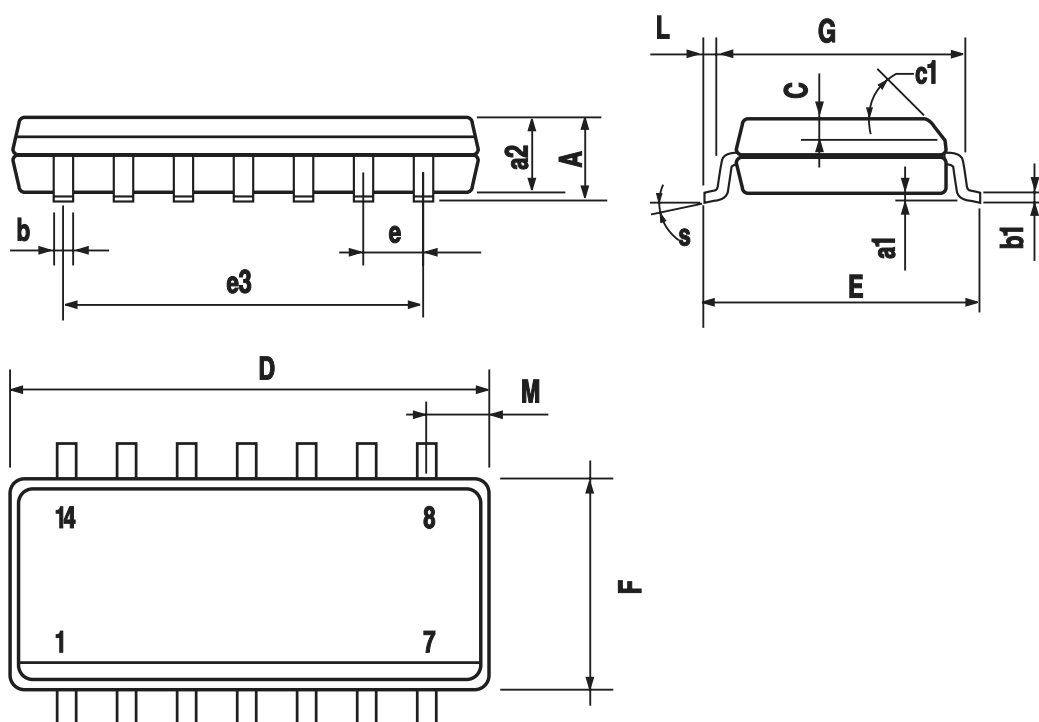
Plastic DIP-14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



SO-14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					



PO13G

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